VG SERIES VG-502MKI8

SPECUFUCATION

Wafer Size Grinding Method		3" to 8"	, PAT.1868779
		Continuous down feed	
Grinding Spindles	Number of spindles Spindle speed Type of spindle bearing Spindle motor Spindle grinding feed speed Spindle up/down feed motor	2 AxIs Max. 3600 rpm Air bearing 2.2 kW 4P built-in type, inverter drive 1 to 999 μ/min 200 W AC Servo motor	
Index Table	Number of vacuum chuck Speed of vacuum chuck Vacuum chuck driving motor Index motor	4 rotary chuck table 1 to 999 rpm 1.1 kW AC Servo motor 0.4 kW	
Automatic Sizing Device	Wafer thickness measuring system Wafer minimum setting size	2 point system in-process gauge 1 μm	
Table Cleaning Device	Table cleaning system	Wafer + Brush cleaning(Ceramic block)	
Wafer cleaning Device	Wafer cleaning system	Wafer + Brush and Spinner	
Automatic Loading and Unloading Device	Number of cassettes Wafer size Wafer address	Horizontally 2 cassettes Max, 8" inches Provided	
Vacuum Pump Unit (option)	Vacuum pump Pressure Exhaust Water supply	1.5kW 40 Torr 40 m³/hr. 5 liter/min (city water)	
Utilities	Electricity supply Grounding resistance Noise Wattage Water supply for grinding Water supply for cleaning Air supply	3 phase AC200V 50A Less 100 Ω Less 1000V of 500 ns pulse 17 kVA 12 to 15 liter/min (8"= 20 liter/min) 8 liter/min (any temperature) 60 liter/min 5.5 kgf/cm²G	
Machine size		2700W/1550D/1770H	
Weight	7	3900 kg to 4600 kg	
Through put	depending on setting	6"= 80 pcs/hr., 8"= 70 pcs/hr.	
Grinding Accuracy	Thickness in a wafer Thickness among wafers Roughness	$6''=1.0\mu\text{m}$ or less, $8''=1.5\mu\text{m}$ or less $6''=1.5\mu\text{m}$ or less, $8''=2.0\mu\text{m}$ or less $6''=0.1\mu\text{m}$ Rmax. or less, $8''=0.2\mu\text{m}$ Rmax. or less	